NSN 5962-01-099-6199

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View Online at https://aerobasegroup.com/nsn/5962-01-099-6199 **Body Length:** 0.960 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.130 inches and 0.185 inches **Maximum Power Dissipation Rating:** 794.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Features Provided:** 3-state output and w/enable and programmable and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Case Outline Source And Designator:** D-6 mil-m-38510 **Current Rating Per Characteristic:** 140.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 85.00 nanoseconds propagation delay time, high to low level output and 40.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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